

## ICeGaN<sup>™</sup> P2 SERIES FOR HIGH-POWER SMPS ENABLING SUPERIOR SYSTEM PERFORMANCE IN DATA CENTRES AND TELECOM APPLICATIONS

# Powering the Future: How Al's Growth Sparks Energy Innovation and GaN Solutions in Data Centres

The explosive growth of AI is leading to a significant increase in energy consumption, prompting technology leaders to prioritise the deployment of AI. This surge is expected to exacerbate the power challenges in data centres, compelling operators to seek solutions that enhance efficiency, energy density, and environmental sustainability. While emerging solutions such as immersion cooling and AI-driven efficiency enhancements address these issues to some extent, GaN-based solutions emerge among top data centre operators to address these growing challenges.

This will lead to a surge in design initiatives focused on GaN, aiming to meet these new efficiency standards.

#### Totem-pole PFC Circuit Diagram



#### Data Centre Power Supply Architecture





80.2°C

Discrete GaN

961°C ICeGaN<sup>1</sup>

80.2 °C

∲ 96.1°C 89.8

22.7

### ICeGaN<sup>™</sup> Enables Lower Losses with Increased Reliability

12 mn

13 mm

ICeGaN™'s driving circuit uses fewer components, allowing for more space for cooling. This design enables the device to operate at lower temperatures, thus improving system reliability and achieving higher output power even with higher R<sub>DS(on)</sub> than competitive discrete e-Mode GaN devices. Enhanced performance is supported by a reduction in R<sub>DS(on)</sub> increase due to lower operating temperature and lower reverse conduction losses thanks to the Miller Clamp enabling 0 V turn off.

#### Product Portfolio

1

ICs

4x smaller

**PCB** area

18 mr

34 mm

PN	R <sub>DS(on)</sub> typ (mΩ)	Current Rating (A)	Package	Features	Preferred Gate Driver	Status	BHDFN: BOTTOM-SIDE COOLED
CGD65C025SP2	25	60	BHDFN-9-1	ICeGaN™	Any MOSFET driver	Contact factory	DHDFN: DUAL-SIDE COOLED
CGD65D025SP2	25	60	DHDFN-9-1	ICeGaN™ Dual gate			
CGD65C055SP2	55	27	BHDFN-9-1	ICeGaN™			
CGD65D055SP2	55	27	DHDFN-9-1	ICeGaN™ Dual gate			222222
<b>BH</b> • Bottom heat-spr	eader <b>DH·</b> D	)ual heat-snre	ader				See product data

() BH: Bottom heat-spreader DH: Dual heat-spreader



Dare to innovate differently

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